EYP-DFB-0780-00080-1500-TOC03-0005

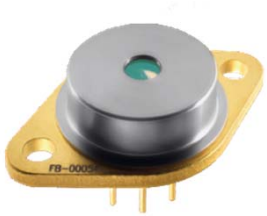
Revision 1.02

2018-03-21

SINGLE FREQUENCY LASER DIODES
Distributed Feedback Laser

General Product Information

Product	Application
780 nm DFB Laser	Spectroscopy (Rb D2 line)
with hermetic 8-Pin TO Package (RoHS compliant)	Metrology
including Monitor Diode, Thermoelectric Cooler and Thermistor	THz Generation



Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max	Measurement Conditions / Comments
Storage Temperature	T_S	°C	-40		85	Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.
Operational Temperature at Case	T_C	°C	-20		75	
Operational Temperature at Laser Chip	T_{LD}	°C	0		50	
Forward Current	I_F	mA			200	
Reverse Voltage	V_R	V			2	
Output Power	P_{opt}	mW			100	
TEC Current	I_{TEC}	A			1.8	
TEC Voltage	V_{TEC}	V			3.2	

Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max	Measurement Conditions / Comments
Operational Temperature at Case	T_{case}	°C	-20		65	
Operational Temperature at Laser Chip	T_{LD}	°C	5		40	measured by integrated Thermistor
Forward Current	I_F	mA			180	
Output Power	P_{opt}	mW	20		80	

Characteristics at T_{LD} = 25° C at BOL

Parameter	Symbol	Unit	min	typ	max	Measurement Conditions / Comments
Center Wavelength	λ_C	nm	779	780	781	see images on page 4
Target Wavelength	λ_T	nm		780.24		reached within T_{LD} = 15 ° ... 45° C at 80 mW
Linewidth (FWHM)	$\Delta\lambda$	MHz		0.6	1	
Sidemode Supression Ratio	SMSR	dB	30	45		P_{opt} = 80 mW
Temperature Coefficient of Wavelength	$d\lambda / dT$	nm / K		0.06		
Current Coefficient of Wavelength	$d\lambda / dI$	nm / mA		0.003		
Mode-hop free Tuning Range	$\Delta\lambda_{tune}$	pm	25			> 10 GHz, at target wavelength

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Characteristics at T_{LD} = 25° C at BOL cont'd

Parameter	Symbol	Unit	min	typ	max	Measurement Conditions / Comments
Laser Current @ P_{opt} = 80 mW	I_{LD}	mA			180	
Slope Efficiency	η	W / A	0.6	0.8	1.1	
Threshold Current	I_{th}	mA			70	
Divergence parallel (FWHM)	$\Theta_{\parallel}$	°		8		parallel to short axis of the housing (see p. 3)
Divergence perpendicular (FWHM)	$\Theta_{\perp}$	°		21		parallel to long axis of the housing (see p. 3)
Degree of Polarization	DOP	%		90		80 mW; E field parallel to long axis of housing

Monitor Diode

Parameter	Symbol	Unit	min	typ	max	Measurement Conditions / Comments
Monitor Detector Responsivity	I_{mon} / P_{opt}	µA/mW	1		20	U_R = 5 V

Thermoelectric Cooler

Parameter	Symbol	Unit	min	typ	max	Measurement Conditions / Comments
Current	I_{TEC}	A		0.4		P_{opt} = 80 mW, ΔT = 20 K
Voltage	U_{TEC}	V		0.8		P_{opt} = 80 mW, ΔT = 20 K
Power Dissipation (total loss at case)	P_{loss}	W		0.5		P_{opt} = 80 mW, ΔT = 20 K
Temperature Difference	ΔT	K			50	P_{opt} = 80 mW, ΔT = |Tcase - TLD|

Thermistor (Standard NTC Type)

Parameter	Symbol	Unit	min	typ	max	Measurement Conditions / Comments
Resistance	R	kΩ		10		T_{LD} = 25° C
Beta Coefficient	β			3892		$R_1 / R_2 = e^{\beta (1/T_1 - 1/T_2)}$ at T_{LD} = 0° … 50° C
Steinhart & Hart Coefficient A	A			1.1293×10^{-3}		$1/T = A + B(\ln R) + C(\ln R)^3$
Steinhart & Hart Coefficient B	B			2.3410×10^{-4}		T: temperature in Kelvin
Steinhart & Hart Coefficient C	C			8.7755×10^{-8}		R: resistance at T in Ohm

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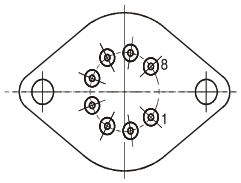
Pin Assignment

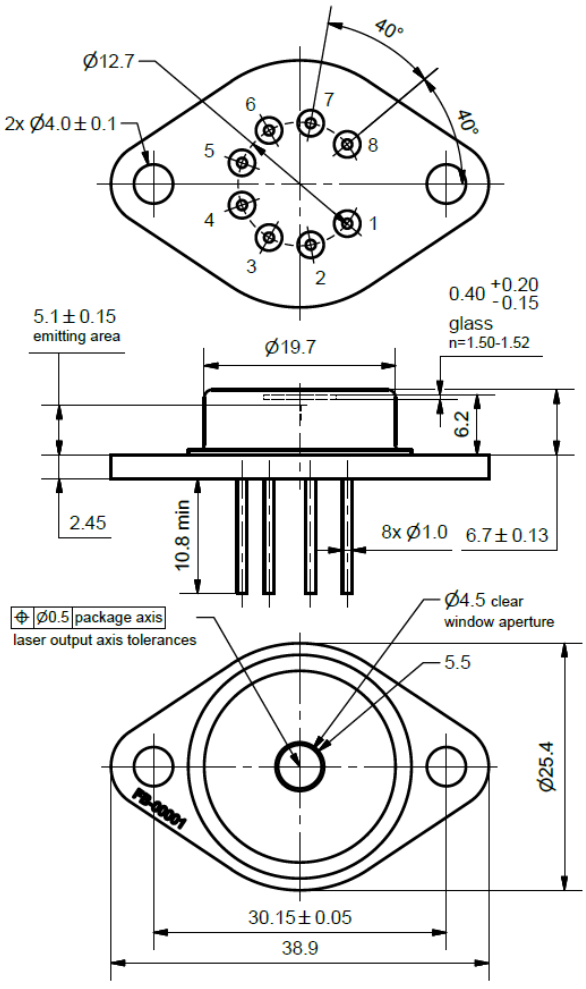
1	Thermoelectric Cooler (+)	5	Laser Diode Anode
2	Thermistor	6	Monitor Diode Anode
3	Thermistor	7	Photo Diode Cathode
4	Laser Diode Cathode	8	Thermoelectric Cooler (-)

All 8 pins are isolated from case.

bottom view



Package Drawings



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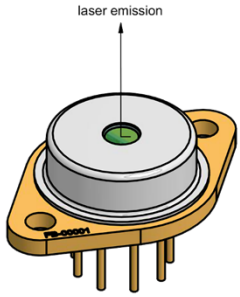
laser emission



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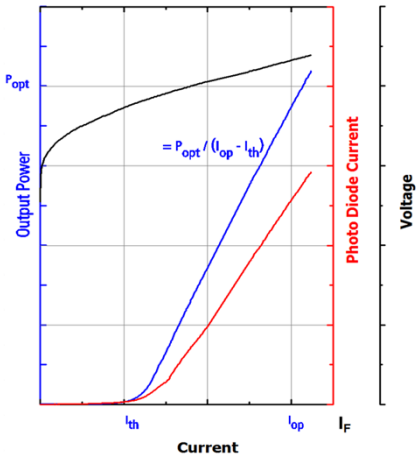
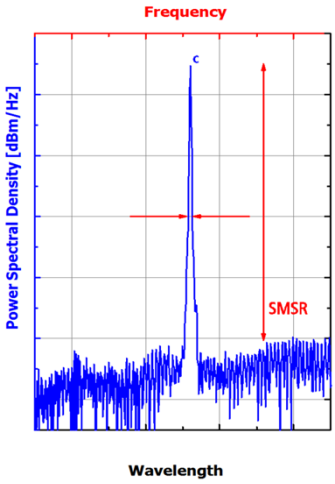
Typical Measurement Results

Output Power vs. Current



Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Ordering Information:

XSoptix
800 Village Walk #316
Guilford, CT 06437
Ph: 203-401-8093
Email orders to: sales@xsoptix.com
Fax orders to: 800-878-7282

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The DFB laser is sensitive against optical feedback, so an optical isolator may be required in order to avoid any disturbance of the emission spectrum. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.

Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

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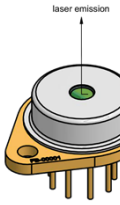

INVISIBLE LASER RADIATION
AVOID EYE OR SKIN EXPOSURE
TO DIRECT OR SCATTERED RADIATION
CLASS 4 LASER PRODUCT
WAVELENGTH 780 nm
MAX. OUTPUT POWER 100 mW

IEC-60825-0

DANGER
INVISIBLE LASER RADIATION
AVOID EYE OR SKIN EXPOSURE TO
DIRECT OR SCATTERED RADIATION
GaAs SEMICONDUCTOR LASER DIODE
100 mW MAX OUTPUT AT 780 nm
CLASS IV LASER PRODUCT

Complies with 21 CFR 1040.10 and 1040.40

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